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Lee et al.

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(54) **DISPLAY AND METHOD OF MANUFACTURING THE SAME**

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(58) **Field of Classification Search**
None
See application file for complete search history.

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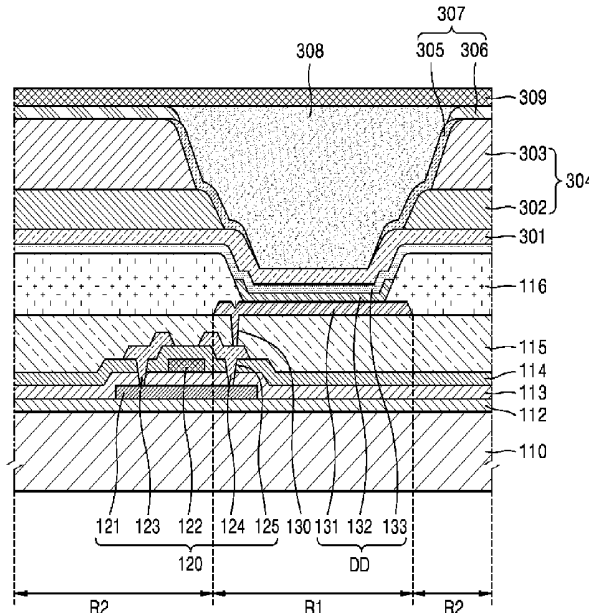
(51) **Int. Cl.**
H01L 27/32 (2006.01)
H01L 51/56 (2006.01)
(Continued)

(52) **U.S. Cl.**
CPC *H01L 27/3272* (2013.01); *H01L 27/322* (2013.01); *H01L 27/3246* (2013.01); *H01L 51/5253* (2013.01); *H01L 51/5284* (2013.01); *H01L 51/56* (2013.01); *H01L 51/0097*

(57) **ABSTRACT**

An organic light-emitting display and a method of manufacturing the same are provided. An organic light-emitting display includes: a substrate including a light-emission region and a non-light-emission region around the light-emission region; a display device on the light-emission region of the substrate; and an encapsulation member on the display device. The encapsulation member includes a light-shielding member including a first light-shielding layer and a second light-shielding layer, the first light-shielding layer being in a region corresponding to the non-light-emission region, and the second light-shielding layer being on the first light-shielding layer; and a color conversion member in a region corresponding to the light-emission region.

20 Claims, 9 Drawing Sheets



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FIG. 1A

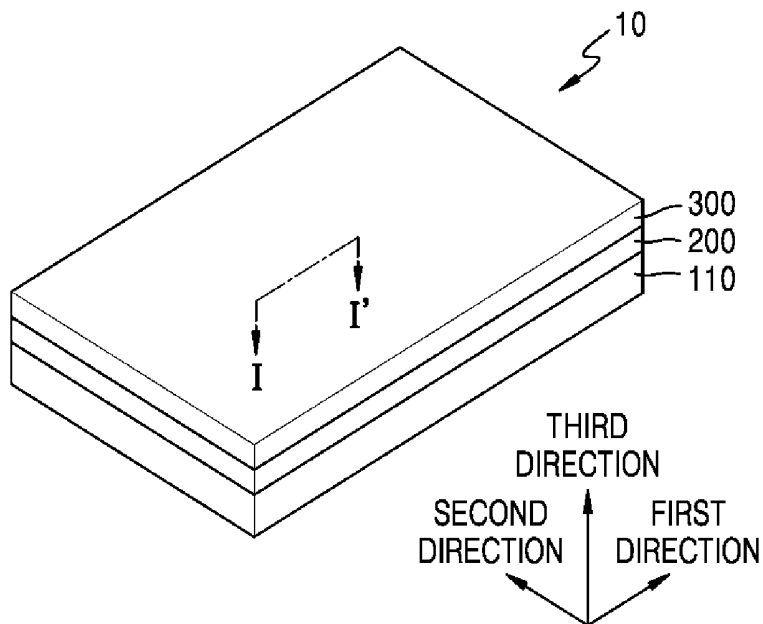


FIG. 1B

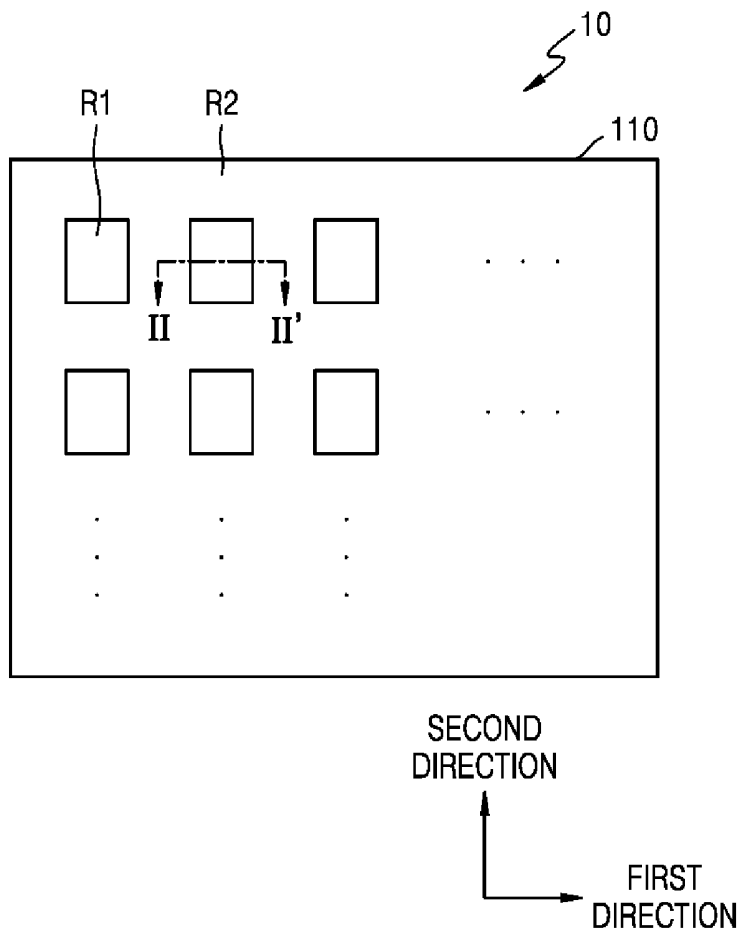


FIG. 1C

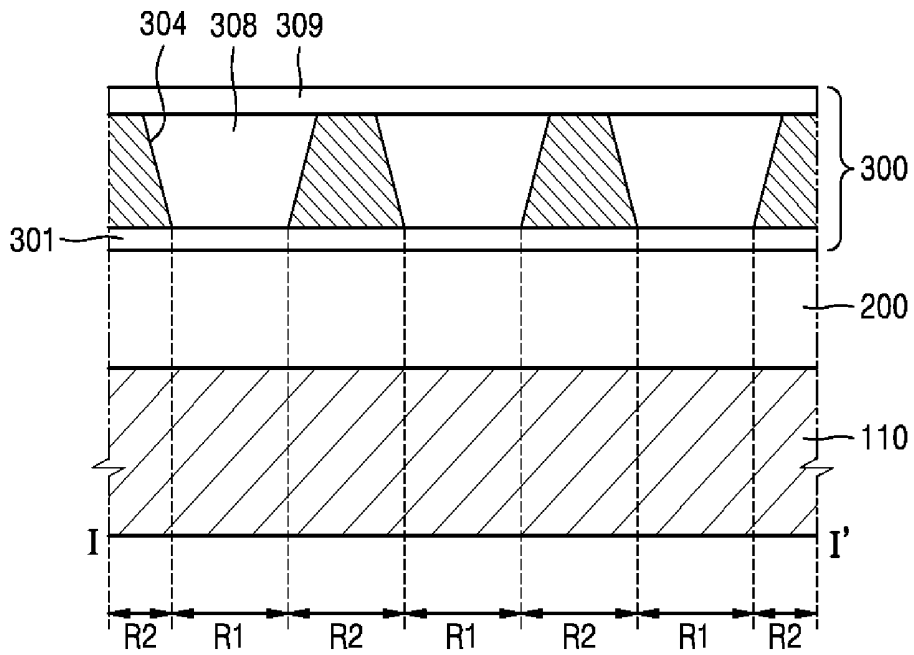


FIG. 2A

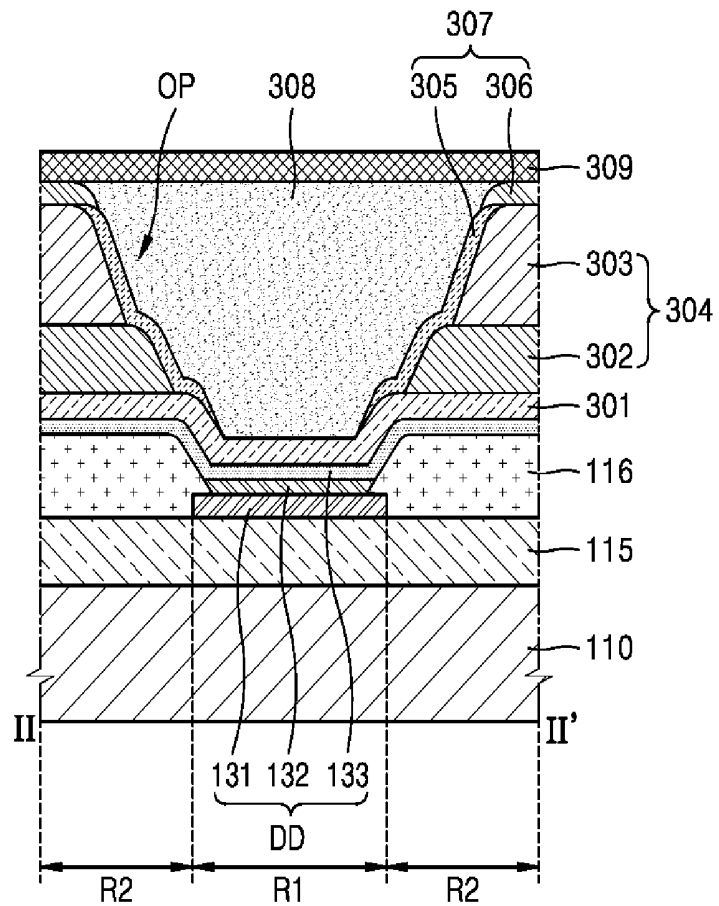


FIG. 2B

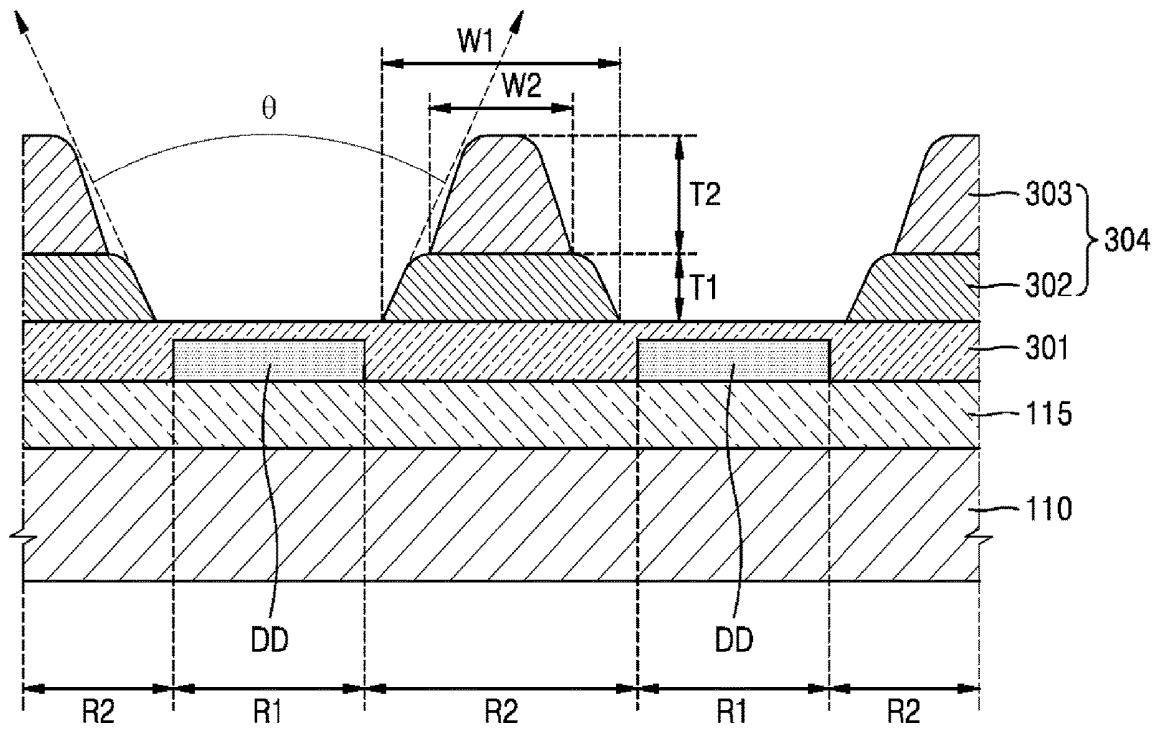


FIG. 3

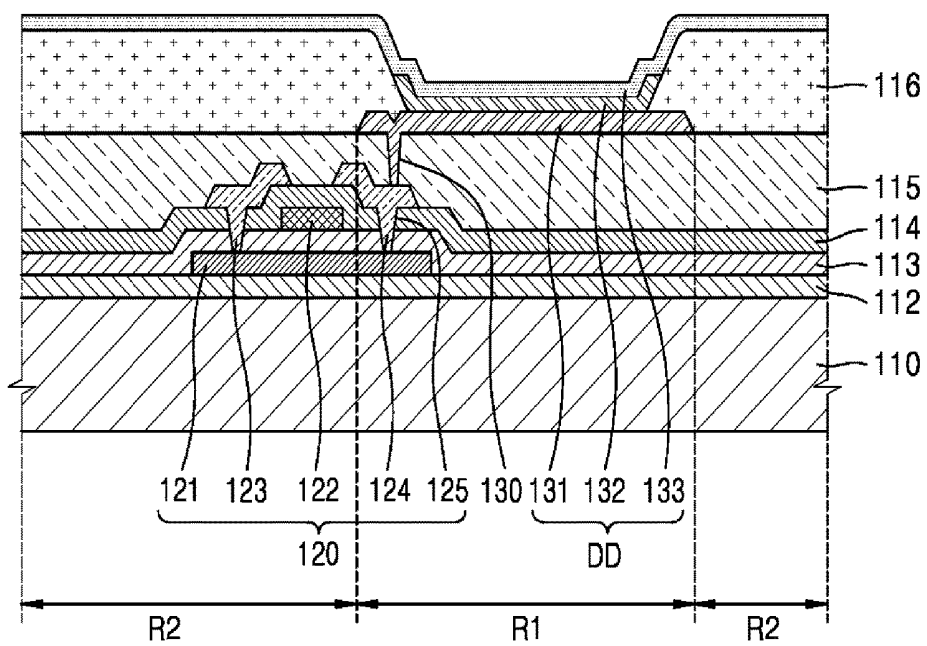


FIG. 4

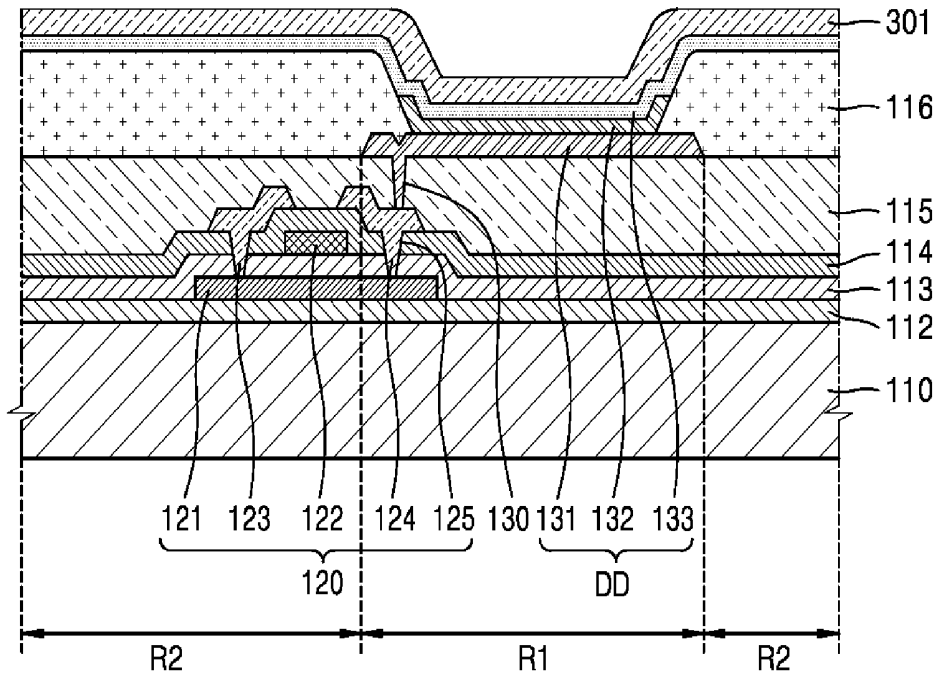


FIG. 5

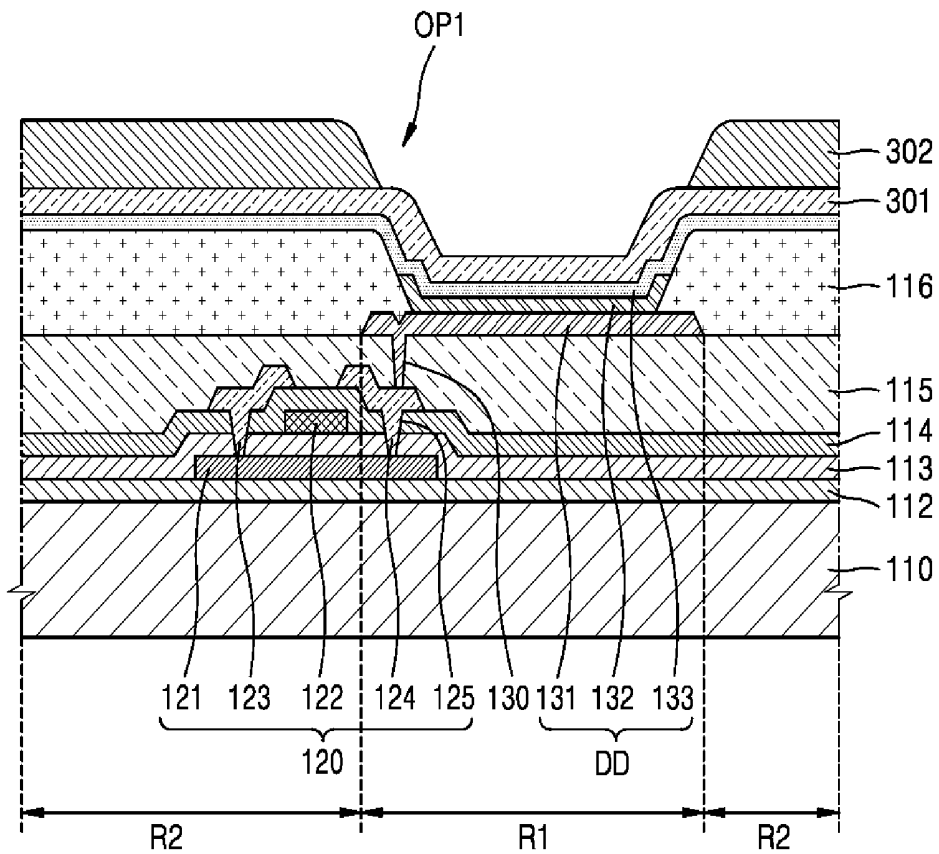


FIG. 6

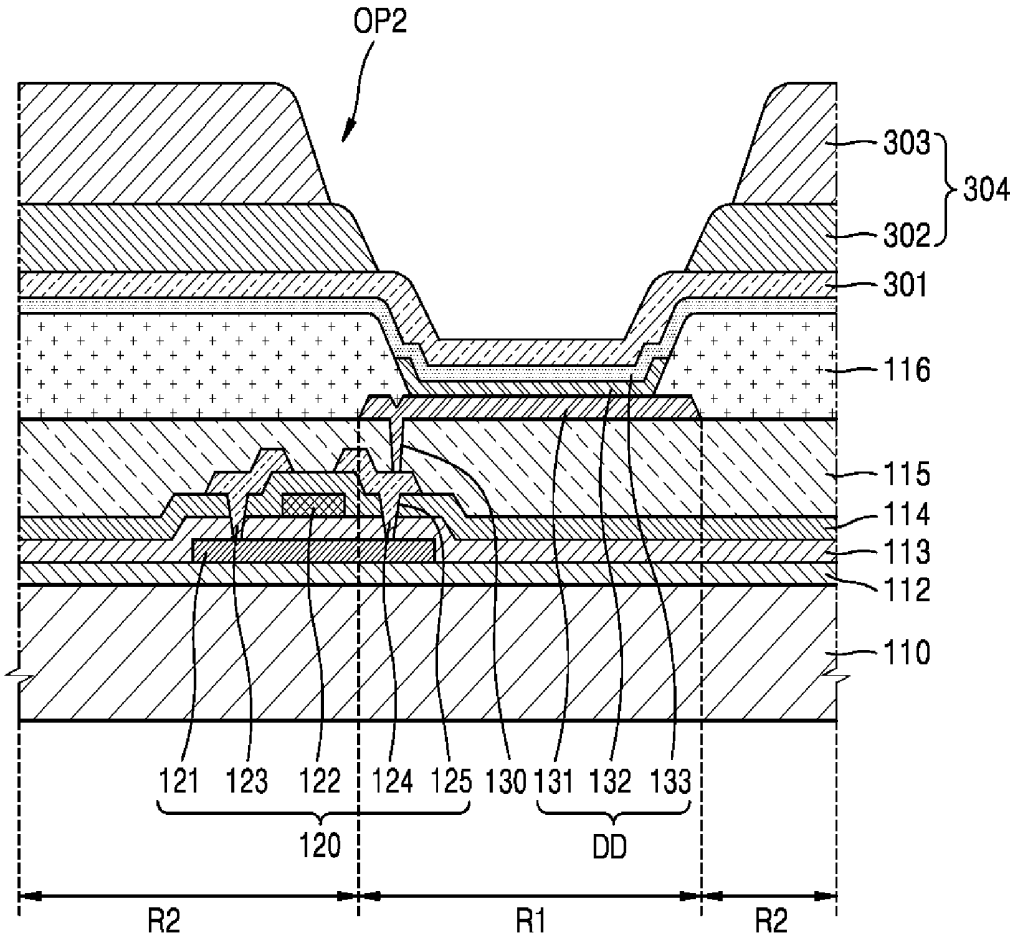


FIG. 7

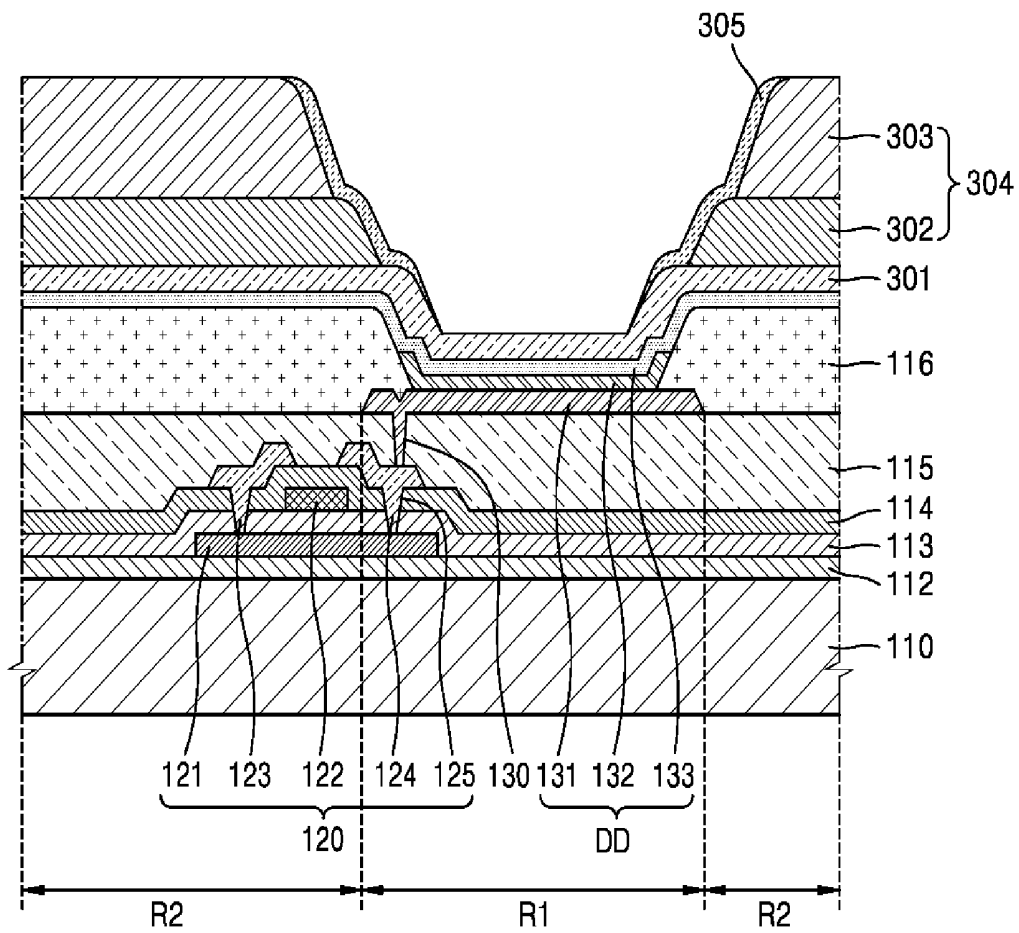


FIG. 8

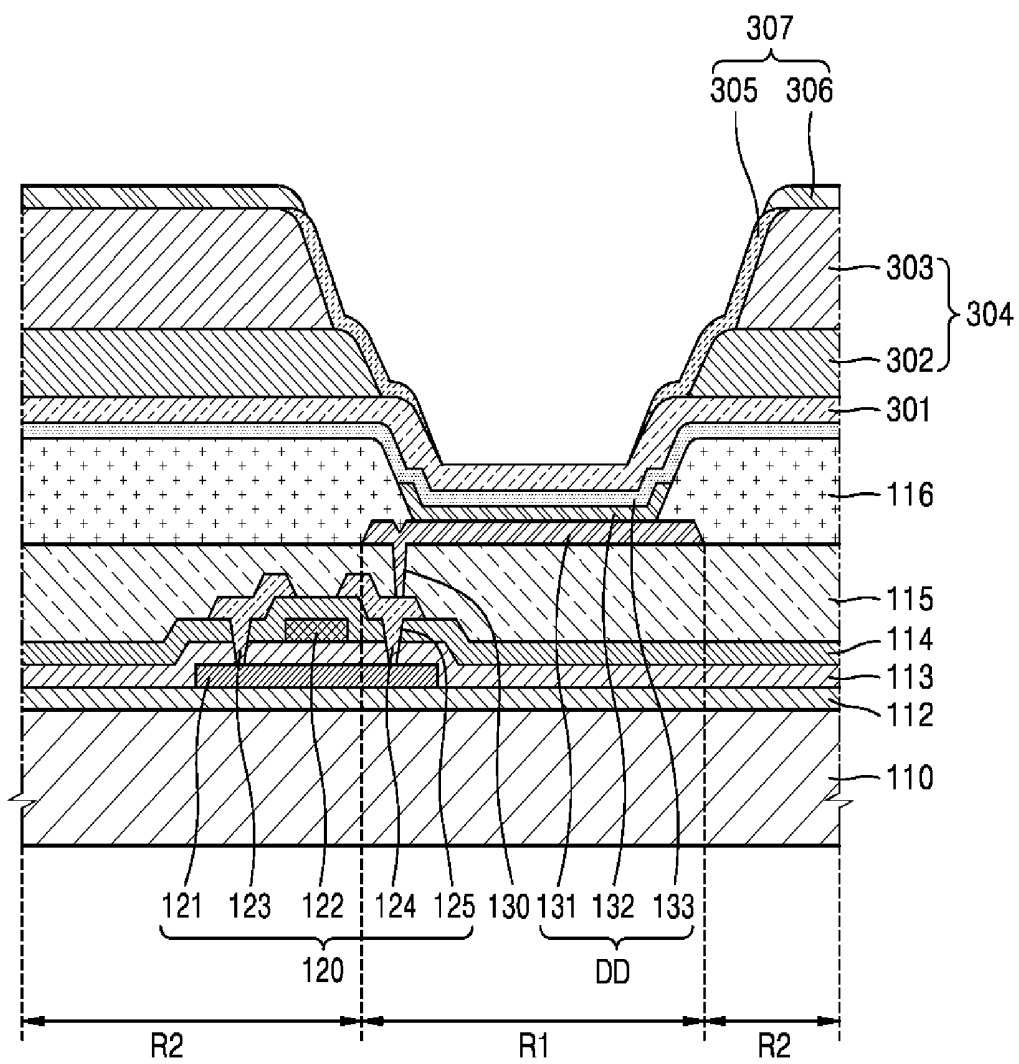


FIG. 9

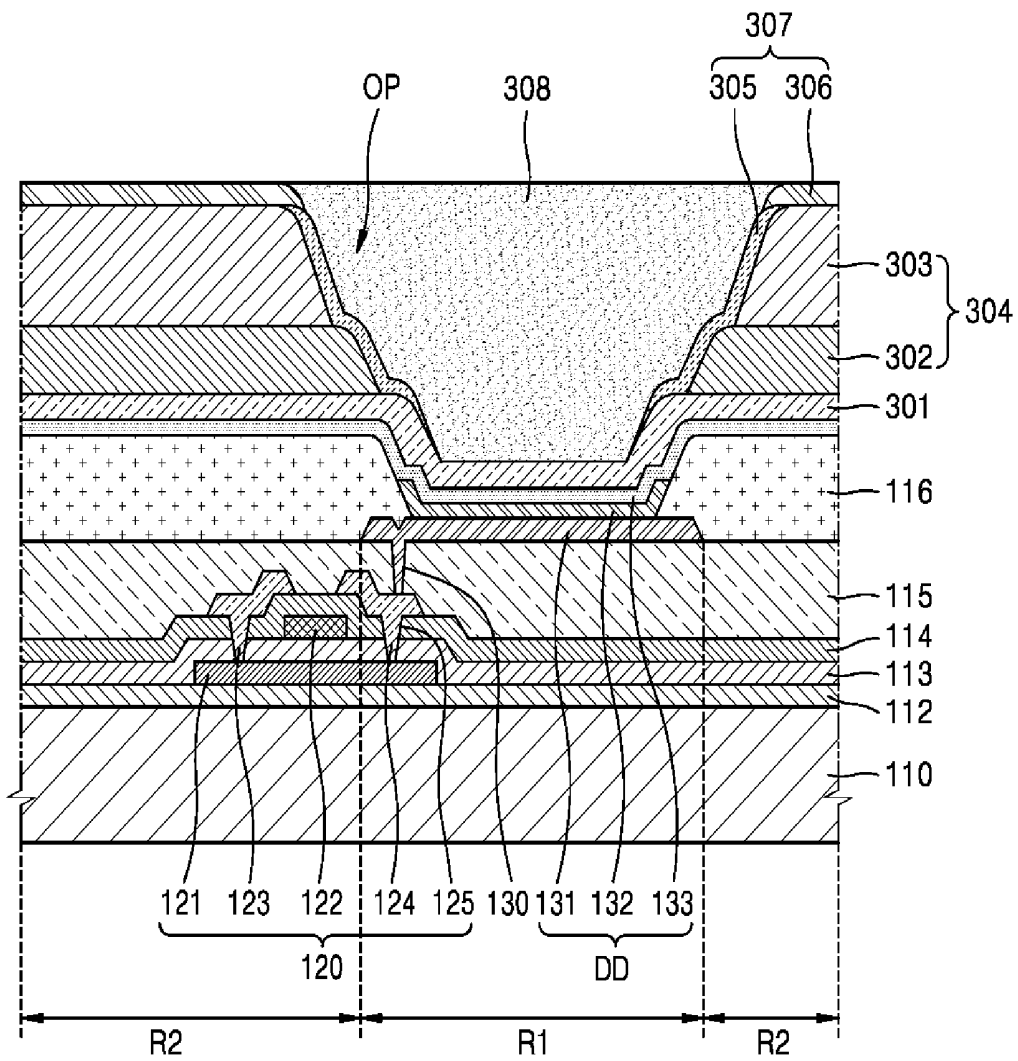
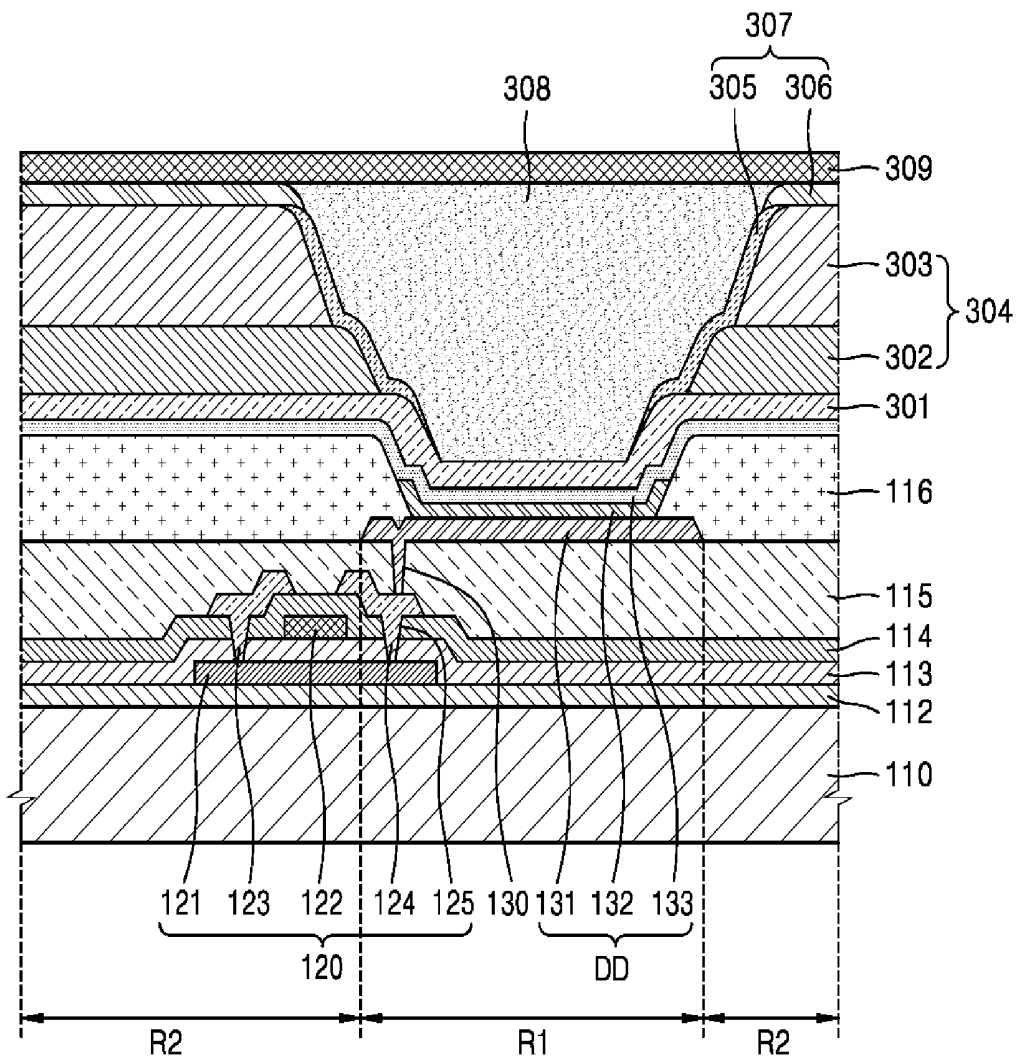


FIG. 10



DISPLAY AND METHOD OF MANUFACTURING THE SAME

CROSS-REFERENCE TO RELATED PATENT APPLICATION

This application claims priority to and the benefit of Korean Patent Application No. 10-2017-0176478, filed on Dec. 20, 2017 in the Korean Intellectual Property Office, the entire disclosure of which is incorporated herein by reference.

BACKGROUND

1. Field

Aspects of one or more embodiments relate to an organic light-emitting display and a method of manufacturing the same.

2. Description of the Related Art

The market for liquid crystal displays (LCDs), organic light-emitting displays (OLEDs), etc. including thin film transistors (TFTs) is being expanded to displays for use in mobile devices. Such displays for use in mobile devices need to be thin, lightweight, and resistant to breakage. To manufacture thin and lightweight displays, a method of fabricating a display from a glass substrate and then thinning the glass substrate according to a mechanical or chemical method has been introduced instead of a method of using a thin glass substrate. However, this process is complicated, and, further, displays manufactured in this manner are fragile. Therefore, actual use of this process is difficult.

SUMMARY

According to an aspect of one or more embodiments, a display apparatus has a reduced thickness and improved luminescent efficiency.

Additional aspects will be set forth, in part, in the description which follows and, in part, will be apparent from the description, or may be learned by practice of the presented embodiments.

According to one or more embodiments, an organic light-emitting display includes: a substrate including a light-emission region and a non-light-emission region around the light-emission region; a display device on the light-emission region of the substrate; and an encapsulation member on the display device, wherein the encapsulation member includes a light-shielding member including a first light-shielding layer and a second light-shielding layer, the first light-shielding layer being in a region corresponding to the non-light-emission region, and the second light-shielding layer being on the first light-shielding layer; and a color conversion member in a region corresponding to the light-emission region.

The encapsulation member may further include a first protection layer between the display device and the light-shielding member.

The first protection layer may include an inorganic material.

The organic light-emitting display may further include a first liquid repellent pattern between the light-shielding member and the color conversion member; and a second liquid repellent pattern on the second light-shielding layer.

The first liquid repellent pattern may include a hydrophilic material, and the second liquid repellent pattern may include a hydrophobic material.

The organic light-emitting display may further include a second protection layer on the light-shielding member and the color conversion member.

The second protection layer may include an inorganic material.

A width of the first light-shielding layer may be greater than a width of the second light-shielding layer, and a thickness of the second light-shielding layer may be greater than a thickness of the first light-shielding layer.

The second light-shielding layer may be located outside an opening formed in the first light-shielding layer, the opening corresponding to the light-emission region.

According to one or more embodiments, an organic light-emitting display includes: a substrate; a first electrode on the substrate; a first insulating film covering an edge of the first electrode; an intermediate layer on the first electrode and including an emission layer; a second electrode covering the intermediate layer and facing the first electrode; a second insulating layer covering the second electrode; a light-shielding member including a first light-shielding layer and a second light-shielding layer, the first light-shielding layer being on the second insulating layer and having a first opening through which a portion of the second insulating layer corresponding to the emission layer is exposed, and the second light-shielding layer being on the first light-shielding layer and having a second opening through which the first opening and an edge of the first light-shielding layer are exposed; and a color conversion member within the first and second openings.

The organic light-emitting display may further include a first liquid repellent pattern on respective lateral surfaces of the first and second openings; and a second liquid repellent pattern on the second light-shielding layer.

The first liquid repellent pattern may include a hydrophilic material, and the second liquid repellent pattern may include a hydrophobic material.

The organic light-emitting display may further include a third insulating layer on the light-shielding member and the color conversion member.

The third insulating layer may include an inorganic material.

A width of the first light-shielding layer may be greater than a width of the second light-shielding layer, and a thickness of the second light-shielding layer may be greater than a thickness of the first light-shielding layer.

According to one or more embodiments, a method of manufacturing an organic light-emitting display includes: providing a substrate including a light-emission region and a non-light-emission region around the light-emission region; forming a display device on the light-emission region of the substrate; forming a first protection layer covering the display device; forming a light-shielding member on the first protection layer, the light-shielding member including a first light-shielding layer and a second light-shielding layer, wherein the first light-shielding layer is in a region corresponding to the non-light-emission region, and the second light-shielding layer is on the first light-shielding layer; and forming a color conversion member in a region corresponding to the light-emission region, wherein the color conversion member is formed on the first light-shielding layer.

The method may further include, after the forming of the light-shielding member, forming a first liquid repellent pattern on respective lateral surfaces of the first and second

light-shielding layers; and forming a second liquid repellent pattern on the second light-shielding layer.

The forming of the light-shielding member may include forming the first light-shielding layer on the first protection layer, the first light-shielding layer including a first opening through which a portion of the first protection layer corresponding to the light-emission region is exposed; and forming the second light-shielding layer outside the first opening of the first light-shielding layer, the second light-shielding layer including a second opening through which an edge of the first light-shielding layer is exposed.

The method may further include forming a third insulating layer on the light-shielding member and the color conversion member.

A width of the first light-shielding layer may be greater than a width of the second light-shielding layer, and a thickness of the second light-shielding layer may be greater than a thickness of the first light-shielding layer.

BRIEF DESCRIPTION OF THE DRAWINGS

The above and/or other aspects will become apparent and more readily appreciated from the following description of some embodiments, taken in conjunction with the accompanying drawings in which:

FIG. 1A is a perspective view of a display according to an embodiment;

FIG. 1B is a schematic plan view of the display of FIG. 1A according to an embodiment;

FIG. 1C is a partial cross-sectional view taken along the line I-I' of the display of FIG. 1A;

FIG. 2A is a partial cross-sectional view taken along the line II-II' of the display of FIG. 1B;

FIG. 2B is a partial cross-sectional view for explaining a light-shielding member, according to an embodiment; and

FIGS. 3 through 10 are cross-sectional views schematically illustrating a method of manufacturing a display, according to an embodiment.

DETAILED DESCRIPTION

Reference will now be made in further detail to some embodiments, examples of which are illustrated in the accompanying drawings, wherein like reference numerals refer to like elements throughout. In this regard, the present embodiments may have different forms and should not be construed as being limited to the descriptions set forth herein. Accordingly, the embodiments are described below, by referring to the figures, to explain aspects of the present description. As used herein, the term "and/or" includes any and all combinations of one or more of the associated listed items. Expressions such as "at least one of," when preceding a list of elements, modify the entire list of elements and do not modify the individual elements of the list.

As the present invention allows for various changes and numerous embodiments, particular embodiments will be illustrated in the drawings and described in further detail in the written description. Herein, effects and features of the present invention and a method for accomplishing them will be described more fully with reference to the accompanying drawings, in which some embodiments of the invention are shown. The present invention may, however, be embodied in many different forms and should not be construed as limited to the embodiments set forth herein.

It is to be understood that although the terms "first," "second," etc. may be used herein to describe various

components, these components should not be limited by these terms. These terms are used to distinguish one component from another.

As used herein, the singular forms "a," "an," and "the" are intended to include the plural forms as well, unless the context clearly indicates otherwise.

It is to be further understood that the terms "comprises" and/or "comprising," as used herein, specify the presence of stated features or components, but do not preclude the presence or addition of one or more other features or components.

It is to be understood that when a layer, region, or component is referred to as being "formed on" another layer, region, or component, it may be directly or indirectly formed on the other layer, region, or component. That is, for example, one or more intervening layers, regions, or components may be present.

Sizes of elements in the drawings may be exaggerated for convenience of explanation. In other words, since sizes and thicknesses of components in the drawings may be arbitrarily illustrated for convenience of explanation, the following embodiments are not limited thereto.

When a certain embodiment may be implemented differently, a specific process order may be performed differently from the described order. For example, two consecutively described processes may be performed substantially at the same time or performed in an order opposite to the described order.

One or more embodiments of the invention will be described below in further detail with reference to the accompanying drawings. Those components that are the same or are in correspondence may be rendered the same reference numeral in various drawings, and redundant descriptions may be omitted.

FIG. 1A is a perspective view of a display 10 according to an embodiment; FIG. 1B is a schematic plan view of the display 10 according to an embodiment; and FIG. 1C is a partial cross-sectional view taken along the line I-I' of the display 10 of FIG. 1A.

Referring to FIGS. 1A to 1C, the display 10 includes a substrate 110, a display unit 200 positioned on the substrate 110, and an encapsulation member 300 covering the display unit 200. The substrate 110, the display unit 200, and the encapsulation member 300 are sequentially stacked on one another in a third direction.

The display 10 may be a liquid crystal display (LCD), an organic light-emitting display (OLED), an electrophoretic display, an electrowetting display panel, or the like. An OLED will be described as an example.

In the display unit 200, a plurality of pixels may be arranged in a first direction and a second direction. Each of the pixels may include a display device, and a pixel circuit electrically connected to the display device. The display devices may be arranged on light-emission regions R1, and the pixel circuits may be arranged on the light-emission regions R1 or a non-light-emission region R2 around the light-emission regions R1. The light-emission regions R1 may be defined as regions corresponding to first electrodes or emission layers of the display devices.

Although the light-emission regions R1 are shown having a quadrilateral shape in FIG. 1B, embodiments are not limited thereto. Each of the light-emission regions R1 may have any of various shapes, such as a polygon, a rectangle, a circle, a cone, an oval, and a triangle.

The encapsulation member 300 may perform a function of encapsulating the display unit 200, and a color conversion function. The encapsulation member 300 may include color

conversion members **308** arranged on the light-emission regions R1, a light-shielding member **304** arranged on the non-light-emission region R2, and a second protection layer **309**.

Although not shown in the drawings, on the encapsulation member **300**, a window may be coupled to the encapsulation member **300** via a pressure sensitive adhesive (PSA). The display **10** may provide an encapsulation function, and a brightness enhancing function based on reflectance control, by using the encapsulation member **300** without using special optical members.

An optical member, such as a polarization film or a phase difference film, may reduce the luminescent efficiency of a display by refracting or reflecting internal light emitted by display devices. The display **10** may improve luminescent efficiency by omitting an optical member and also may reduce reflectance of external light by including the color conversion members **308**. Thus, the display **10** may have improved visibility.

Because an optical member is generally provided in the form of a film, the optical member has a thickness equal to or greater than a certain thickness. Moreover, an adhesion layer may be additionally needed to apply an optical film to a display. Accordingly, a display including an encapsulation layer and a special optical film may thicken and thus may influence flexibility of the display. In the display **10**, the color conversion members **308** may be arranged directly on the substrate **110** and thus provide both an encapsulation function and a function of an optical member. This may reduce the thickness of the display **10**. Accordingly, a thin display may be realized, and a flexible (foldable or rollable) display may be easily realized.

FIG. 2A is a partial cross-sectional view taken along the line II-II' of FIG. 1B of the display **10**.

Referring to FIG. 2A, the display **10** may include the display unit **200** having pixels arranged on the substrate **110**, and the encapsulation member **300** on the display unit **200**. Each of the pixels may include a display device DD arranged on a light-emission region R1, and a pixel circuit (not shown) electrically connected to the display device DD.

The display device DD may include a first electrode **131**, a second electrode **133** opposite to the first electrode **131**, and an intermediate layer **132** between the first electrode **131** and the second electrode **133**. Although not shown in FIG. 2A, the first electrode **131** may be electrically connected to a pixel circuit below the first electrode **131**.

The encapsulation member **300** may include a first protection layer **301**, the light-shielding member **304**, the color conversion members **308**, and the second protection layer **309**. The color conversion members **308** may overlap the light-emission regions R1, and the light-shielding member **304** may overlap the non-light-emission region R2.

The first protection layer **301** may cover the display devices DD and may be disposed on the light-emission regions R1 and the non-light-emission region R2. In an embodiment, the first protection layer **301** may include at least one inorganic film. In an embodiment, the first protection layer **301** may be omitted.

The light-shielding member **304** may be arranged directly on the first protection layer **301** and thus may contact an upper surface of the first protection layer **301**. In an embodiment, when the first protection layer **301** is omitted, the light-shielding member **304** may be arranged directly on the second electrode **133** and thus may contact an upper surface of the second electrode **133**. The light-shielding member **304** may include a first light-shielding layer **302** and a second

light-shielding layer **303**. The first light-shielding layer **302** and the second light-shielding layer **303** may be stepped.

FIG. 2B is a partial cross-sectional view for explaining the light-shielding member **304**, according to an embodiment.

Referring to FIG. 2B, the first light-shielding layer **302** may have a first thickness T1 and a first width W1 and may be disposed on the non-light-emission region R2. The second light-shielding layer **303** may have a second thickness T2 and a second width W2 and may be disposed on the non-light-emission region R2. The second thickness T2 may be greater than the first thickness T1. The first width W1 may be greater than the second width W2. The second light-shielding layer **303** may be disposed on the first light-shielding layer **302** and may be formed to be retreated from an edge of the first light-shielding layer **302**.

The first width W1 of the first light-shielding layer **302** may be a width of a bottom surface of the first light-shielding layer **302**, and a lateral surface of the first light-shielding layer **302** may be inclined with respect to the bottom surface thereof. The second width W2 of the second light-shielding layer **303** may be a width of a bottom surface of the second light-shielding layer **303**, and a lateral surface of the second light-shielding layer **303** may be inclined with respect to the bottom surface thereof.

The first thickness T1 and the first width W1 of the first light-shielding layer **302** may be determined such that a viewing angle (8) relative to a luminance ratio may be secured. The second thickness T2 of the second light-shielding layer **303** may be determined such that color mixing of light beams produced from neighboring light-emission regions R1 may be prevented or substantially prevented. The second width W2 may be determined such that the viewing angle (8) relative to the luminance ratio may be secured based on the first width W1.

The first light-shielding layer **302** and the second light-shielding layer **303** may include a material that absorbs at least a portion of light, a light reflection material, or a light scattering material. In an embodiment, the first light-shielding layer **302** and the second light-shielding layer **303** may include an opaque material, such as including an organic resin, a resin or paste including glass paste and a black pigment, metal particles (e.g., any of nickel, aluminum, molybdenum, and an alloy thereof), metal oxide particles (for example, chromium oxide), or metal nitride particles (for example, chromium nitride).

In an embodiment, the first light-shielding layer **302** may include a low-reflection inorganic material. In an embodiment, the second light-shielding layer **303** may include a low-reflection organic material.

The color conversion members **308** may be disposed within openings OP defined by the light-shielding member **304** and thus may fill the openings OP. In an embodiment, the light-shielding members **308** may be disposed directly on the first protection layer **301** within the openings OP and thus may contact the upper surface of the first protection layer **301**.

The color conversion members **308** may be color filters having different colors corresponding to the respective pixels of the light-emission regions R1. For example, the color conversion members **308** may include red, green, and blue color filters. According to another embodiment, the color conversion members **308** may include color filters having four or more colors. The color conversion members **308** may include a low-reflection and low-temperature color filter material. In an embodiment, the color conversion members **308** may include a pigment of 40% or more within a solid.

In an embodiment, a liquid repellent pattern **307** may be included between the light-shielding member **304** and the color conversion members **308**. The liquid repellent pattern **307** may include a first liquid repellent pattern **305** and a second liquid repellent pattern **306**.

The first liquid repellent pattern **305** may be formed along lateral surfaces of the openings OP. The first liquid repellent pattern **305** may cover a portion of the first protection layer **301**, a lateral surface of the first light-shielding layer **302**, and a lateral surface of the second light-shielding layer **303**. The first liquid repellent pattern **305** has an affinity with the color conversion members **308** and thus may have a hydrophilic property to prevent or substantially prevent the color conversion members **308** from not completely filling the openings OP. In an embodiment, the first liquid repellent pattern **305** may include polyacrylamide photo resist, polyethylenimine photo resist, or the like.

The second liquid repellent pattern **306** may cover an upper surface of the second light-shielding layer **303**. The second liquid repellent pattern **306** may have a hydrophobic property in order to prevent or substantially prevent color conversion members **308** of neighboring light-emission regions R1 from mixing with each other. In an embodiment, the second liquid repellent pattern **306** may include a fluorinated silane promoter, a fluorinated acryl monomer, a fluorinated alkyl photo resist, or the like.

The second protection layer **309** is disposed on the color conversion members **308** and protects the color conversion members **308**. The second protection layer **309** may cover the light-emission regions R1 and the non-light-emission region R2 and may be disposed on the upper surface of the second light-shielding layer **303** and upper surfaces of the color conversion members **308**. In an embodiment, the second protection layer **309** may include at least one inorganic film. In an embodiment, the second protection layer **309** may be omitted.

FIGS. 3 through 10 are cross-sectional views schematically illustrating a method of manufacturing a display, according to an embodiment.

Referring to FIG. 3, a plurality of pixels may be formed on a substrate **110**. Each of the pixels may include a display device DD, and a pixel circuit including a thin film transistor (TFT) **120** electrically connected to the display device DD. The display device DD may be formed on a light-emission region R1, and the pixel circuit may be formed on a non-light-emission region R2. The display device DD may be an organic light-emitting diode (OLED).

A buffer layer **112** may be formed on the substrate **110**, and then a semiconductor layer may be formed and patterned on the buffer layer **112** to thereby form an active layer **121** of the TFT **120**.

The substrate **110** may be formed of any of various materials, such as glass, plastic, or metal. According to an embodiment, the substrate **110** may include a flexible substrate.

The buffer layer **112** may be formed of at least one of an organic layer and an inorganic layer. For example, the buffer layer **112** may perform functions of blocking impurity elements from being permeated through the substrate **110**, and planarizing the surface of the substrate **110**, and may be formed of an inorganic material, such as silicon nitride (SiN_x) and/or silicon oxide (SiO_x), and as a single layer or multiple layers. In an embodiment, the buffer layer **112** may be omitted.

The semiconductor layer may include any of various materials. For example, the semiconductor layer may include an inorganic semiconductor material, such as amor-

phous silicon or crystalline silicon. As another example, the semiconductor layer may contain an oxide semiconductor or an organic semiconductor material.

Thereafter, a first insulating layer **113** may be formed on the active layer **121**, and then a first conductive layer may be formed and patterned on the first insulating layer **113** to thereby form a gate electrode **122**.

In an embodiment, the first insulating layer **113** may be an inorganic insulation layer. In an embodiment, the first insulating layer **113** may be formed of at least one insulating material selected from SiO₂, SiN_x, SiON, Al₂O₃, TiO₂, Ta₂O₅, HfO₂, ZrO₂, BST, and PZT, in a single-layered or multi-layered structure.

The first conductive layer may be formed of any of various conductive materials. In an embodiment, the first conductive layer may be formed of at least one of aluminum (Al), platinum (Pt), palladium (Pd), silver (Ag), magnesium (Mg), gold (Au), nickel (Ni), neodymium (Nd), iridium (Ir), chromium (Cr), calcium (Ca), molybdenum (Mo), titanium (Ti), tungsten (W), and copper (Cu), in a single-layered or multi-layered structure.

A second insulating layer **114** may be formed on the gate electrode **122** and then patterned to thereby form contact holes **125** respectively exposing portions of a source region and a drain region of the active layer **121**.

In an embodiment, the second insulating layer **114** may be an inorganic insulation layer. In an embodiment, the second insulating layer **114** may be formed of at least one insulating material selected from SiO₂, SiN_x, SiON, Al₂O₃, TiO₂, Ta₂O₅, HfO₂, ZrO₂, BST, and PZT, in a single-layered or multi-layered structure. According to another embodiment, the second insulating layer **114** may be an organic insulation layer.

A second conductive layer may be formed on the second insulating layer **114** and then patterned to thereby form a source electrode **123** and a drain electrode **124** that respectively contact the source region and the drain region of the active layer **121**.

In an embodiment, the second conductive layer may be formed of a same material as a material used to form the first conductive layer, and as a single layer or multiple layers. For example, the second conductive layer may be formed of at least one of aluminum (Al), platinum (Pt), palladium (Pd), silver (Ag), magnesium (Mg), gold (Au), nickel (Ni), neodymium (Nd), iridium (Ir), chromium (Cr), calcium (Ca), molybdenum (Mo), titanium (Ti), tungsten (W), and copper (Cu).

A third insulating layer **115** may be formed on the source electrode **123** and the drain electrode **124** and then patterned to thereby form a via hole **130** through which a portion of one of the source electrode **123** and the drain electrode **124** is exposed.

In an embodiment, the third insulating layer **115** may be formed of an organic insulating material, and as a single layer or multiple layers. In an embodiment, the third insulating layer **115** may include a commercial polymer such as polymethyl methacrylate (PMMA) or polystyrene (PS), a polymer derivative having a phenol group, an acryl-based polymer, an imide-based polymer, an acryl ether-based polymer, an amide-based polymer, a fluorine-based polymer, a p-xylene-based polymer, a vinyl alcohol-based polymer, a blend thereof, or the like. For example, the third insulating layer **115** may include polyimide, polyamide (PA), acryl resin, or the like.

An OLED electrically connected to the TFT **120** may be formed on the third insulating layer **115**.

A first electrode **131** may be formed by forming and patterning a third conductive layer on the third insulating layer **115**, and may be electrically connected to one of the source electrode **123** and the drain electrode **124** through the via hole **130**.

In an embodiment, the third conductive layer may include a reflection layer formed of silver (Ag), magnesium (Mg), aluminum (Al), platinum (Pt), palladium (Pd), gold (Au), nickel (Ni), neodymium (Nd), iridium (Ir), chromium (Cr), or a compound thereof, and a transparent or semi-transparent electrode layer formed on the reflection layer.

A fourth insulating layer **116** exposing at least a portion of the first electrode **131** and covering an edge of the first electrodes **131** may be formed on the first electrode **131**.

In an embodiment, the fourth insulating layer **116** may be formed of the aforementioned inorganic or organic insulating material, and as a single layer or multiple layers.

An intermediate layer **132** may be formed on the exposed portion of the first electrode **131**, and a second electrode **133** opposite to the first electrode **131** may be formed on the intermediate layer **132**.

In an embodiment, the intermediate layer **132** includes at least an emission layer (EML) and may further include a least one functional layer from among a hole injection layer (HIL), a hole transport layer (HTL), an electron transport layer (ETL), and an electron injection layer (EIL), in addition to the EML.

In an embodiment, the EML may be a red emission layer, a green emission layer, or a blue emission layer. Alternatively, to emit white light, the EML may have a multi-layered structure in which a red emission layer, a green emission layer, and a blue emission layer are stacked, or may have a single-layered structure including a red emission material, a green emission material, and a blue emission material.

Although the intermediate layer **132** is shown patterned to correspond to only the first electrode **131** in FIG. 3, this illustration is for convenience of explanation, and the intermediate layer **132** may be integrally formed with an intermediate layer **132** of a display device DD of an adjacent light-emission region R1. Alternatively, at least one layer of the intermediate layer **132** may be formed for each light-emission region R1 and at least one other layer thereof may be integrally formed with the intermediate layer **132** of the adjacent light-emission region R1. In this way, various modifications may be made.

In an embodiment, the second electrode **133** may include a layer formed of a material selected from the group consisting of lithium (Li), calcium (Ca), lithium fluoride/calcium (LiF/Ca), lithium fluoride/aluminum (LiF/Al), aluminum (Al), magnesium (Mg), and a compound thereof, and may also include, on the layer, an auxiliary electrode or bus electrode line formed of a transparent electrode forming material selected from the group consisting of ITO, IZO, ZnO, and In₂O₃. In an embodiment, the second electrode **133** may be formed on an entire surface of the display unit **200** including the light-emission regions R1 and the non-light-emission region R2.

The display device DD may be disposed such as not to overlap the TFT **120** or may be disposed such as to partially overlap the TFT **120**.

Referring to FIG. 4, a first protection layer **301** may be formed on the second electrode **133**.

In an embodiment, the first protection layer **301** may include at least one inorganic film. In an embodiment, the first protection layer **301** may be formed on the second

electrode **133** by chemical vapor deposition (CVD) or atomic layer deposition (ALD).

Referring to FIG. 5, a first light-shielding layer **302** may be formed on the first protection layer **301** in the non-light-emission region R2.

In an embodiment, a photosensitive layer may be formed by coating an upper surface of the first protection layer **301** with a first light-shielding material, and then may undergo photolithography to thereby form the first light-shielding layer **302** having a first opening OP1. The first opening OP1 may correspond to a light-emission region R1 and may expose a portion of the first protection layer **301** (for example, a portion of the first protection layer **301** that corresponds to the light-emission region R1).

The first opening OP1 may be formed to be larger than an opening through which the first electrode **131** formed on the fourth insulating layer **116** is exposed, and, thus, the first light-shielding layer **302** may be formed to be retreated from an edge of the fourth insulating layer **116** on the side of the light-emission region R1.

In an embodiment, the first light-shielding layer **302** may include an inorganic insulating material, such as inorganic oxide or inorganic nitride (for example, SiOx, SiNx, SiNxOy, AlOx, TiOx, TaOx, ZnOx, or MoTaOx).

In an embodiment, the first light-shielding layer **302** may be formed to be about 200 Å to about 1.0 μm.

Referring to FIG. 6, a second light-shielding layer **303** may be formed on the first light-shielding layer **302**.

In an embodiment, a photosensitive layer may be formed by coating the entire surface of the substrate **110** with a second light-shielding material, and then may undergo photolithography to thereby form the second light-shielding layer **303** having a second opening OP2. The second opening OP2 may be formed to be larger than the first opening OP1 by corresponding to the light-emission region R1 and a portion of the non-light-emission region R2, and may expose a portion of the first protection layer **301** (for example, a portion of the first protection layer **301** that corresponds to the light-emission region R1) and an edge of the first light-shielding layer **302** on the side of the light-emission region R1. Accordingly, the second light-shielding layer **303** may be formed to be retreated from the edge of the first light-shielding layer **302** on the side of the light-emission region R1.

In an embodiment, the second light-shielding layer **303** may be formed of an organic insulating material, such as a thermoplastic resin (e.g., PC, polyethylene terephthalate (PET), polyether sulfone, polyvinyl butyral, polyphenylene ether, polyamide, polyetherimide, norbornene-based resin, methacrylic resin, or cyclic polyolefin series), or a thermosetting resin (e.g., epoxy resin, phenol resin, urethane resin, acrylic resin, vinyl ester resin, imide resin, urethane system resin, urea resin, or melamine resin).

A thickness of the second light-shielding layer **303** may be determined to be a certain height or greater, in consideration of process characteristics and material characteristics of the color conversion members **308**, which are to be formed next. In an embodiment, the second light-shielding layer **303** may be formed to be about 4.0 μm to about 5.0 μm.

Although the first light-shielding layer **302** and the second light-shielding layer **303** are shown sequentially formed in the embodiment of FIGS. 5 and 6, embodiments are not limited thereto. For example, a first light-shielding material and a second light-shielding material may be sequentially stacked and then patterned to thereby form the first light-

shielding layer **302** having the first opening OP1 and the second light-shielding layer **303** having the second opening OP2.

Referring to FIG. 7, a first liquid repellent pattern **305** may be formed on the lateral surface of the light-shielding member **304**.

A liquid repellent material having a hydrophilic property may be coated on the substrate **110** on which the light-shielding member **304** has been formed, and then may be patterned such as to remain only on respective lateral surfaces of the first opening OP1 and the second opening OP2. Thus, the first liquid repellent pattern **305** may be formed.

The first liquid repellent pattern **305** may be formed on the lateral surface of the first protection layer **301** and the respective lateral surfaces of the first and second light-shielding layers **302** and **303**, which are exposed through the first opening OP1 and the second opening OP2.

Referring to FIG. 8, a second liquid repellent pattern **306** may be formed on an upper surface of the light-shielding member **304**.

A liquid repellent material having a hydrophobic property may be coated on the substrate **110** on which the light-shielding member **304** and the first liquid repellent pattern **305** have been formed, and then may be patterned such as to remain only on the upper surface of the light-shielding member **304**, namely, the upper surface of the second light-shielding layer **303**. Thus, the second liquid repellent pattern **306** may be formed.

Referring to FIG. 9, each color conversion member **308** may be formed within an opening OP on which the liquid repellent pattern **307** has been formed (i.e. the first opening OP1 and the second opening OP2).

In an embodiment, the color conversion member **308** may be formed via a solution process, such as dropping or ink-jetting. When ink-jetting is used, the color conversion member **308** may be formed by discharging a color ink including a color conversion material into the opening OP of the light-emission region R1 and then hardening the color ink. The light-shielding member **304** may serve as a dam that confines the color ink.

A color conversion material corresponding to the color of the display device DD formed in the light-emission region R1 may be provided to the opening OP. In an embodiment, a hardening process may be an ultraviolet (UV) ray hardening process or a heat curing process, or the UV hardening process and the heat curing process may be concurrently (e.g., simultaneously) conducted. In this case, the heat curing process may be a low-temperature curing process of 90° or less. Accordingly, during the hardening process, damage to the display device DD may be prevented or substantially prevented, and stability of a process may be improved.

According to an embodiment, the color conversion member **308** is formed via ink-jetting, which is different from photolithography. Accordingly, a mask for forming the color conversion member **308** via photolithography is not needed, and a pre-baking process that is conducted at a high temperature required by photolithography or a developing process exposed to a developing solution, and a subsequent post-baking process may be omitted.

Referring to FIG. 10, a second protection layer **309** may be formed on the substrate **110** on which the color conversion members **308** have been formed.

In an embodiment, the second protection layer **309** may include at least one inorganic film. In an embodiment, the

second protection layer **309** may be formed on the light-shielding member **304** and the color conversion members **308** by CVD or ALD.

In the above-described embodiment, a liquid repellent material is coated on a surface of the light-shielding member **304**. However, according to another embodiment, the light-shielding member **304** may undergo plasma surface treatment, instead of being coated with the liquid repellent material, to thereby improve adhesion with a color solution during formation of the color conversion members **308**, thus stably forming the color conversion members **308**.

One or more embodiments include a display having a reduced thickness and providing improved luminescent efficiency.

It is to be understood that embodiments described herein should be considered in a descriptive sense only and not for purposes of limitation. Descriptions of features or aspects within each embodiment should typically be considered as available for other similar features or aspects in other embodiments.

While one or more embodiments have been described with reference to the figures, it will be understood by those of ordinary skill in the art that various changes in form and details may be made therein without departing from the spirit and scope as set forth by the following claims.

What is claimed is:

1. A display comprising:

a substrate comprising a light-emission region and a non-light-emission region around the light-emission region;

a display device on the light-emission region of the substrate; and

an encapsulation member on the display device, wherein the encapsulation member comprises:

a light-shielding member comprising a first light-shielding layer and a second light-shielding layer, the first light-shielding layer being in a region corresponding to the non-light-emission region, and the second light-shielding layer being on the first light-shielding layer; and

a color conversion member in a region corresponding to the light-emission region, and

wherein the second light-shielding layer is located outside an opening formed in the first light-shielding layer, the opening corresponding to the light-emission region.

2. The display of claim 1, wherein the encapsulation member further comprises a first protection layer between the display device and the light-shielding member.

3. The display of claim 2, wherein the first protection layer comprises an inorganic material.

4. A display comprising:

a substrate comprising a light-emission region and a non-light-emission region around the light-emission region;

a display device on the light-emission region of the substrate;

an encapsulation member on the display device;

a first liquid repellent pattern between the light-shielding member and the color conversion member; and

a second liquid repellent pattern on the second light-shielding layer,

wherein the encapsulation member comprises:

a light-shielding member comprising a first light-shielding layer and a second light-shielding layer, the first light-shielding layer being in a region corresponding to

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the non-light-emission region, and the second light-shielding layer being on the first light-shielding layer; and
 a color conversion member in a region corresponding to the light-emission region. 5
5. The display of claim 4, wherein the first liquid repellent pattern comprises a hydrophilic material, and the second liquid repellent pattern comprises a hydrophobic material. 10
6. The display of claim 1, further comprising a second protection layer on the light-shielding member and the color conversion member.
7. The display of claim 6, wherein the second protection layer comprises an inorganic material. 15
8. The display of claim 1, wherein a width of the first light-shielding layer is greater than a width of the second light-shielding layer, and a thickness of the second light-shielding layer is greater than a thickness of the first light-shielding layer. 20
9. A display comprising:
 a substrate;
 a first electrode on the substrate;
 a first insulating layer covering an edge of the first electrode; 25
 an intermediate layer on the first electrode and comprising an emission layer;
 a second electrode covering the intermediate layer and facing the first electrode; 30
 a second insulating layer covering the second electrode;
 a light-shielding member comprising a first light-shielding layer and a second light-shielding layer, the first light-shielding layer being on the second insulating layer and having a first opening through which a portion of the second insulating layer corresponding to the emission layer is exposed, and the second light-shielding layer being on the first light-shielding layer and having a second opening through which the first opening and an edge of the first light-shielding layer are exposed; and 40
 a color conversion member within the first and second openings.
10. The display of claim 9, further comprising:
 a first liquid repellent pattern on respective lateral surfaces of the first and second openings; and 45
 a second liquid repellent pattern on the second light-shielding layer.
11. The display of claim 10, wherein the first liquid repellent pattern comprises a hydrophilic material, and the second liquid repellent pattern comprises a hydrophobic material. 50
12. The display of claim 9, further comprising a third insulating layer on the light-shielding member and the color conversion member. 55
13. The display of claim 12, wherein the third insulating layer comprises an inorganic material.

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14. The display of claim 9, wherein a width of the first light-shielding layer is greater than a width of the second light-shielding layer, and a thickness of the second light-shielding layer is greater than a thickness of the first light-shielding layer.
15. A method of manufacturing a display, the method comprising:
 providing a substrate comprising a light-emission region and a non-light-emission region around the light-emission region;
 forming a display device on the light-emission region of the substrate;
 forming a light-shielding member on the display device, the light-shielding member comprising a first light-shielding layer and a second light-shielding layer, wherein the first light-shielding layer is in a region corresponding to the non-light-emission region, and the second light-shielding layer is on the first light-shielding layer; and
 forming a color conversion member in a region corresponding to the light-emission region, wherein the color conversion member is formed on the first light-shielding layer,
 wherein the second light-shielding layer is located outside an opening formed in the first light-shielding layer, the opening corresponding to the light-emission region.
16. The method of claim 15, further comprising, after the forming of the light-shielding member:
 forming a first liquid repellent pattern on respective lateral surfaces of the first and second light-shielding layers; and
 forming a second liquid repellent pattern on the second light-shielding layer.
17. The method of claim 15, wherein the forming of the light-shielding member comprises:
 forming the first light-shielding layer on the display device, the first light-shielding layer comprising the opening through which a portion of the display device corresponding to the light-emission region is exposed; and
 forming the second light-shielding layer outside the opening of the first light-shielding layer, the second light-shielding layer comprising another opening through which an edge of the first light-shielding layer is exposed.
18. The method of claim 15, further comprising forming a second protection layer on the light-shielding member and the color conversion member.
19. The method of claim 15, wherein a width of the first light-shielding layer is greater than a width of the second light-shielding layer, and a thickness of the second light-shielding layer is greater than a thickness of the first light-shielding layer.
20. The method of claim 15, further comprising forming a first protection layer covering the display device, and wherein the forming of the light-shielding member comprises forming the first light-shielding layer on the first protection layer.

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专利名称(译)	显示器及其制造方法		
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[标]申请(专利权)人(译)	三星显示有限公司		
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摘要(译)

提供了一种有机发光显示器及其制造方法。一种有机发光显示器，包括：基板，其包括发光区域和围绕该发光区域的非发光区域；以及发光区域。在基板的发光区域上的显示装置；显示装置上的封装构件。所述封装构件包括：遮光构件，所述遮光构件包括第一遮光层和第二遮光层，所述第一遮光层在与所述非发光区域相对应的区域中；以及所述第二遮光部。层在第一遮光层上；在与发光区域相对应的区域中的颜色转换构件。

